High Voltage Transistor

PNP Silicon

BSS63LT1G, NSVBSS63LT1G

Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	-100	Vdc
Collector – Emitter Voltage R_{BE} = 10 k Ω	V _{CER}	-110	Vdc
Collector Current – Continuous	Ι _C	-100	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board, (Note 1) $T_A = 25^{\circ}C$ Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance Junction-to-Ambient	R_{\thetaJA}	556	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) $T_A = 25^{\circ}C$ Derate above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T _J , T _{stg}	−55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

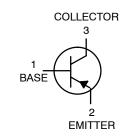
1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in.

2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.



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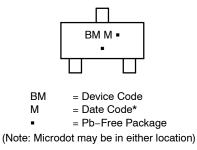
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CASE 318 STYLE 6

MARKING DIAGRAM



*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
BSS63LT1G	SOT–23 (Pb–free)	3000 / Tape & Reel
NSVBSS63LT1G	SOT–23 (Pb–free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

BSS63LT1G, NSVBSS63LT1G

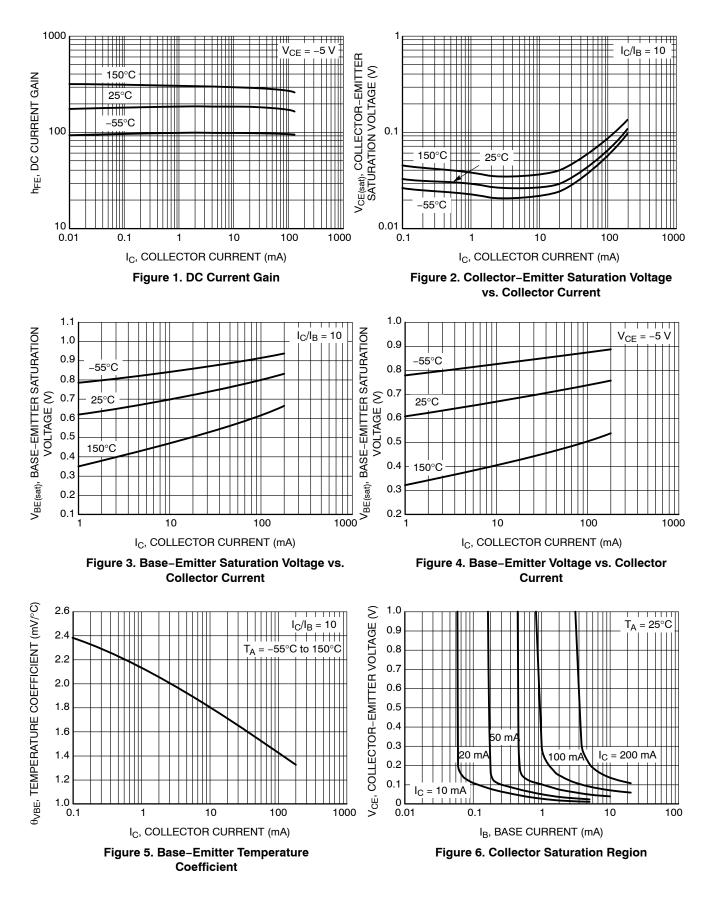
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage ($I_C = -100 \ \mu Adc$)	V _{(BR)CEO}	-100	_	-	Vdc
Collector – Emitter Breakdown Voltage (I _C = –10 μ Adc, I _E = 0, R _{BE} = 10 kΩ)	V _{(BR)CER}	-110	_	_	Vdc
Collector – Base Breakdown Voltage $(I_E = -10 \ \mu Adc, I_E = 0)$	V _{(BR)CBO}	-110	_	_	Vdc
Emitter – Base Breakdown Voltage ($I_E = -10 \ \mu Adc$)	V _{(BR)EBO}	-6.0	_	-	Vdc
Collector Cutoff Current ($V_{CB} = -90$ Vdc, $I_E = 0$)	I _{CBO}	_	_	-100	nAdc
Collector Cutoff Current (V _{CE} = -110 Vdc, R _{BE} = 10 k Ω)	I _{CER}	_	_	-10	μAdc
Emitter Cutoff Current (V _{EB} = -6.0 Vdc, $I_C = 0$)	I _{EBO}	_	_	-200	nAdc
ON CHARACTERISTICS					
DC Current Gain (I _C = -10 mAdc, V _{CE} = -1.0 Vdc) (I _C = -25 mAdc, V _{CE} = -1.0 Vdc)	h _{FE}	30 30			-
Collector – Emitter Saturation Voltage ($I_C = -25$ mAdc, $I_B = -2.5$ mAdc)	V _{CE(sat)}	_	_	-250	mVdc
Base – Emitter Saturation Voltage ($I_C = -25$ mAdc, $I_B = -2.5$ mAdc)	V _{BE(sat)}	-	-	-900	mVdc
SMALL-SIGNAL CHARACTERISTICS					
Current – Gain – Bandwidth Product ($I_C = -25$ mAdc, $V_{CE} = -5.0$ Vdc, f = 20 MHz)	f _T	50	95	-	MHz
Case Capacitance ($I_E = I_C = 0$, $V_{CB} = -10$ Vdc, f = 1.0 MHz)	C _C	_	_	20	pF
Noise Figure (I_C = -0.2 mA, V_CE = -5.0 Vdc, R _g = 2 kΩ, f = 1.0 kHz, BW = 200 Hz)	NF	-	_	10	dB
Product parametric performance is indicated in the Electrical Characteristics f	or the listed test of	aditiona		nuice noted	Draduat

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in. 2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.

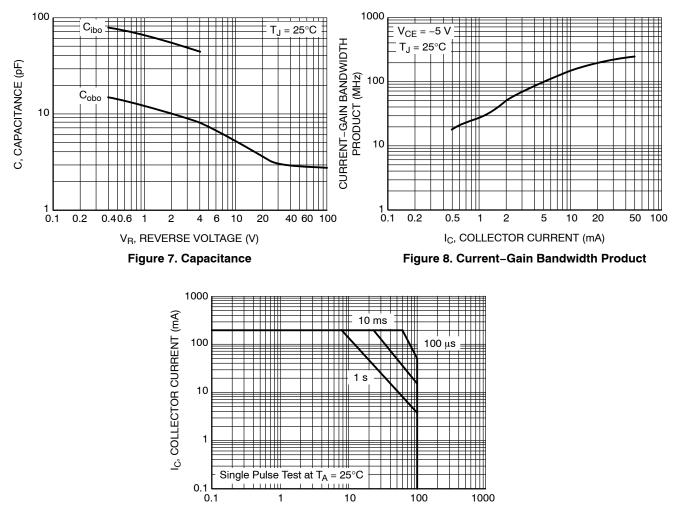
BSS63LT1G, NSVBSS63LT1G

TYPICAL CHARACTERISTICS



BSS63LT1G, NSVBSS63LT1G

TYPICAL CHARACTERISTICS



V_{CE}, COLLECTOR EMITTER VOLTAGE (V)

Figure 9. Safe Operating Area

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

D

3

TOP VIEW

SIDE VIEW

Нe

DETAIL A

-3X b

onsemi



SCALE 4:1

A____ ' A1SOT-23 (TO-236) CASE 318 ISSUE AT

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-L1

DETAIL A

END VIEW

DATE 01 MAR 2023

NDTES

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M,1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS			INCHES		
DIM	MIN.	NDM.	MAX.	MIN.	NDM.	MAX.
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
с	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
Η _E	2.10	2.40	2.64	0.083	0.094	0.104
Т	0*		10*	0*		10*



RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

M = Date Code

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

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MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

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DATE 01 MAR 2023

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE		
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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